Supplementary Information

Controlling Electronic States of Few-walled Carbon Nanotube Yarn via Joule-annealing and *p*-type Doping Towards Large Thermoelectric Power Factor

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Joule Heat (W)	I _G /I _D	I_{2D}/I_G
0 (pristine)	1	0.3
1	1.6	0.5
2	5	0.5
3	11.2	0.5
3.4	15.7	0.4
4	17.8	0.7

Table S1: The values of the intensity ratio of IG/ID and I2D/IG.



Figure S2: Fitted curves of the temperature dependent Seebeck coefficient for (a) pristine, (b) Joule-annealed and (c) Joule-annealing followed by F4TCNQ doped FWCNT yarns.



Figure S3: Relationship between the amount of joule-annealing and the intensity of 2D band to G band in Raman spectroscopy, indication of the formation of multi-layered graphene structure on the surface of FWCNT yarn.



Figure S4: Possible mechanism of morphology-change after Joule-annealing and doping.



Figure S5: Raman spectrum of F4TCNQ.



Figure S6: TEM images of (a) pristine, (b) Joule-annealed, and (c) Joule-annealing followed by 2.5 mg/ml F4TCNQ doped FWCNT yarns.



Figure S7: TGA analysis of the FWCNT yarn before and after Joule-annealing.